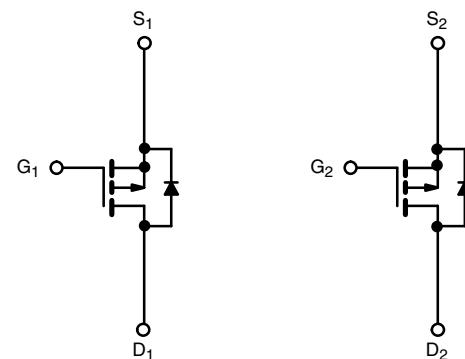
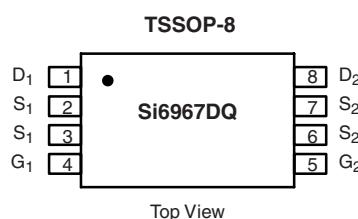


Dual P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
- 8	0.030 at $V_{GS} = - 4.5$ V	± 5.0
	0.045 at $V_{GS} = - 2.5$ V	± 4.0
	0.070 at $V_{GS} = - 1.8$ V	± 3.0

FEATURES

- Halogen-free
- TrenchFET® Power MOSFETs: 1.8 V Rated


RoHS
COMPLIANT


Ordering Information: Si6967DQ-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	- 8	V
Gate-Source Voltage	V_{GS}	± 8	
Continuous Drain Current ($T_J = 150$ °C) ^{a, b}	I_D ($T_A = 25$ °C)	± 5.0	A
	I_D ($T_A = 70$ °C)	± 4.0	
Pulsed Drain Current	I_{DM}	± 30	
Continuous Source Current (Diode Conduction) ^{a, b}	I_S	- 1.25	
Maximum Power Dissipation ^{a, b}	P_D ($T_A = 25$ °C)	1.1	W
	P_D ($T_A = 70$ °C)	0.72	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	$t \leq 10$ s	R_{thJA}	110	°C/W
	Steady State		115	

Notes:

a. Surface Mounted on FR4 board.

b. $t \leq 10$ s.

For SPICE model information via the Worldwide Web: <http://www.vishay.com/www/product/spice.htm>.

SPECIFICATIONS $T_J = 25^\circ\text{C}$, unless otherwise noted

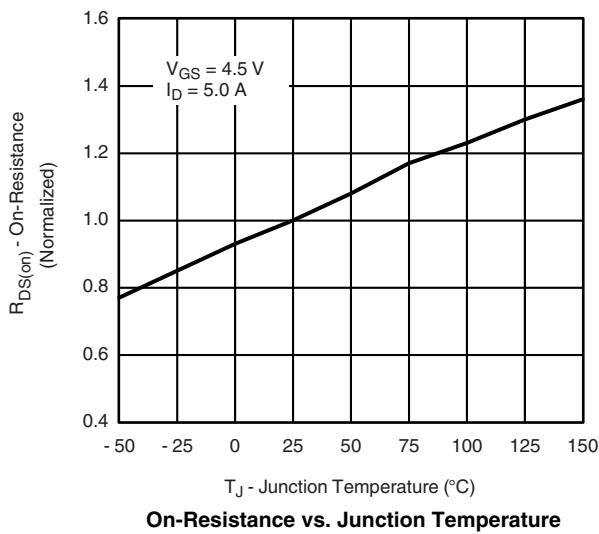
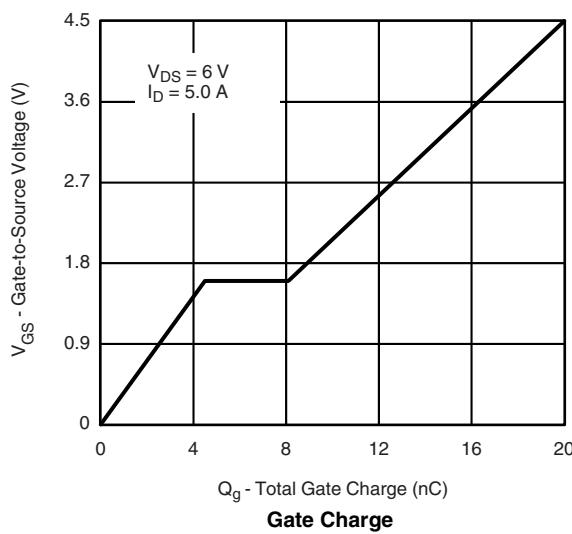
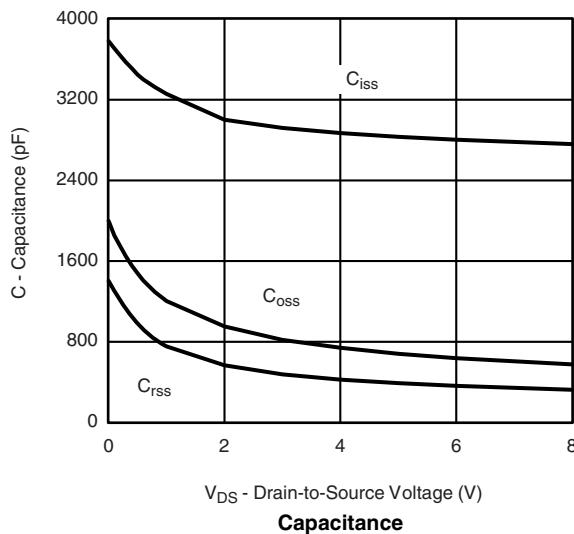
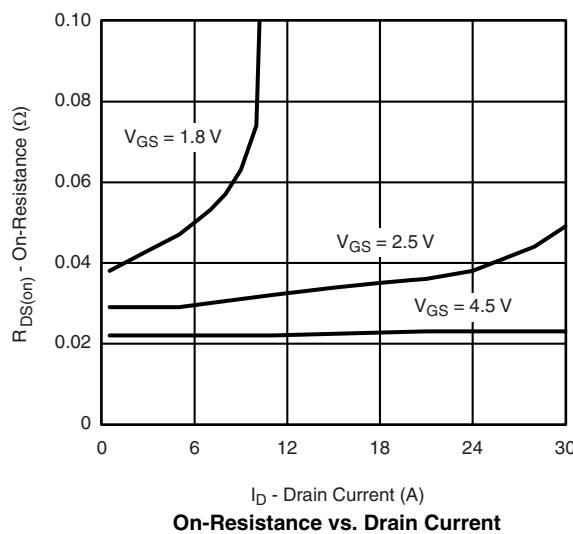
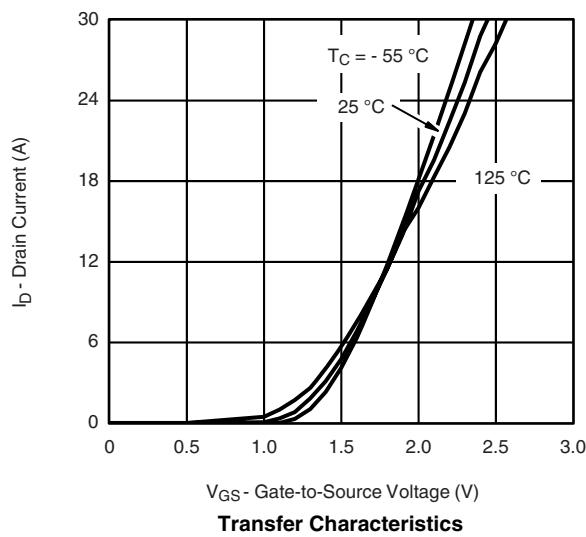
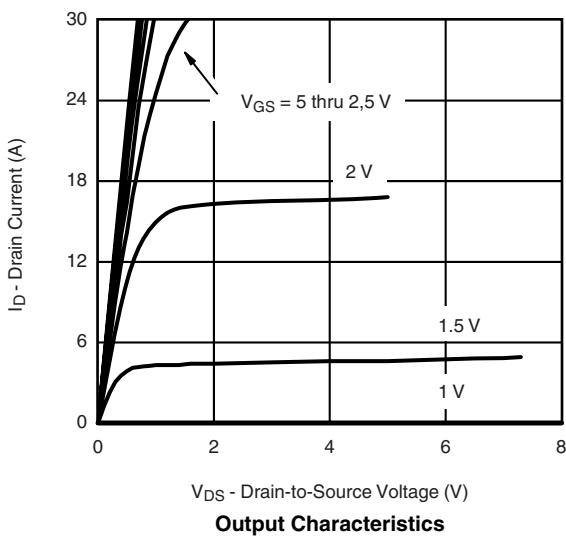
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$, $I_D = -250 \mu\text{A}$	- 0.45			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}$, $V_{GS} = \pm 8 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -6.4 \text{ V}$, $V_{GS} = 0 \text{ V}$		- 1		μA
		$V_{DS} = -6.4 \text{ V}$, $V_{GS} = 0 \text{ V}$, $T_J = 70^\circ\text{C}$			- 25	
On-State Drain Current ^a	$I_{D(\text{on})}$	$V_{DS} \geq -8 \text{ V}$, $V_{GS} = -4.5 \text{ V}$	- 30			A
Drain-Source On-State Resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = -4.5 \text{ V}$, $I_D = -5.0 \text{ A}$		0.024	0.030	Ω
		$V_{GS} = -2.5 \text{ V}$, $I_D = -4.0 \text{ A}$		0.033	0.045	
		$V_{GS} = -1.8 \text{ V}$, $I_D = -3.0 \text{ A}$		0.048	0.070	
Forward Transconductance ^a	g_{fs}	$V_{DS} = -8 \text{ V}$, $I_D = -5.0 \text{ A}$		18		S
Diode Forward Voltage ^a	V_{SD}	$I_S = -1.25 \text{ A}$, $V_{GS} = 0 \text{ V}$		- 0.68	- 1.1	V
Dynamic^b						
Total Gate Charge	Q_g	$V_{DS} = -6 \text{ V}$, $V_{GS} = -4.5 \text{ V}$, $I_D = -5.0 \text{ A}$		20	40	nC
Gate-Source Charge	Q_{gs}			4.5		
Gate-Drain Charge	Q_{gd}			3.6		
Turn-On Delay Time	$t_{d(\text{on})}$	$V_{DD} = -6 \text{ V}$, $R_L = 6 \Omega$ $I_D \equiv -1 \text{ A}$, $V_{GEN} = -4.5 \text{ V}$, $R_G = 6 \Omega$		20	50	ns
Rise Time	t_r			30	60	
Turn-Off Delay Time	$t_{d(\text{off})}$			85	150	
Fall Time	t_f			50	90	
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = -1.25 \text{ A}$, $dI/dt = 100 \text{ A}/\mu\text{s}$		50	100	

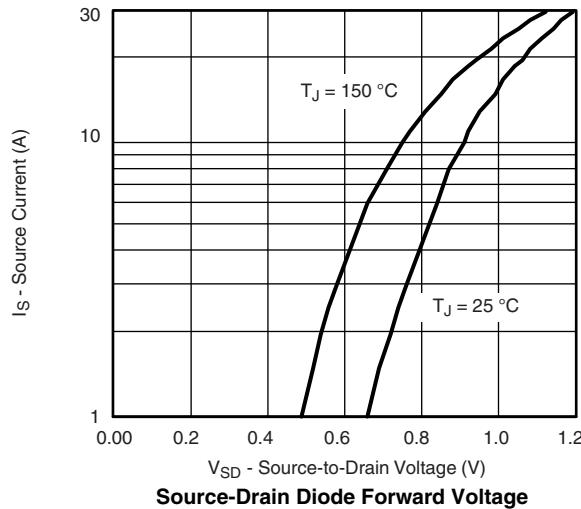
Notes:

a. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2 \%$.

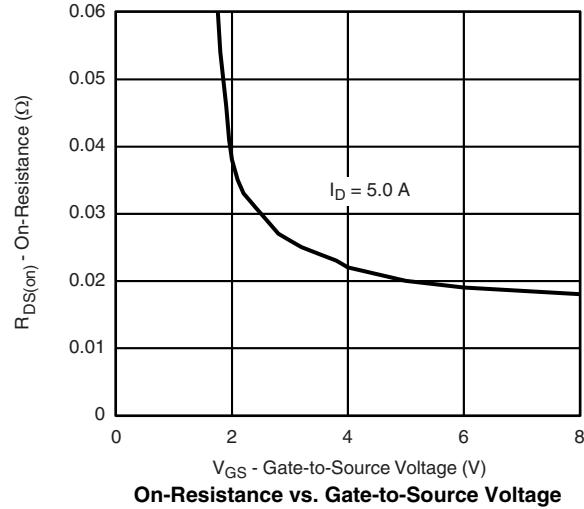
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

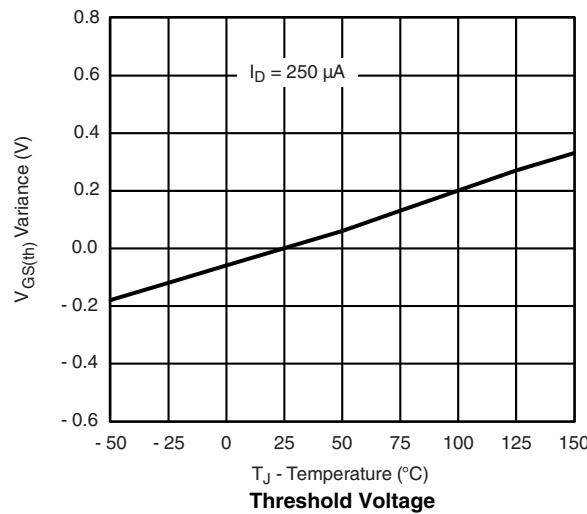
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted


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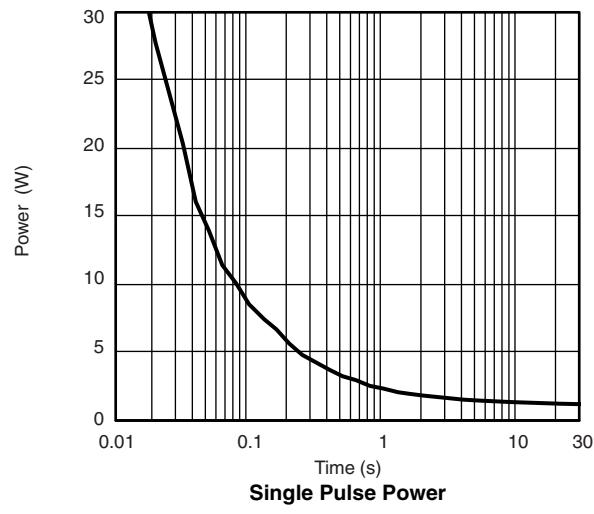
Source-Drain Diode Forward Voltage



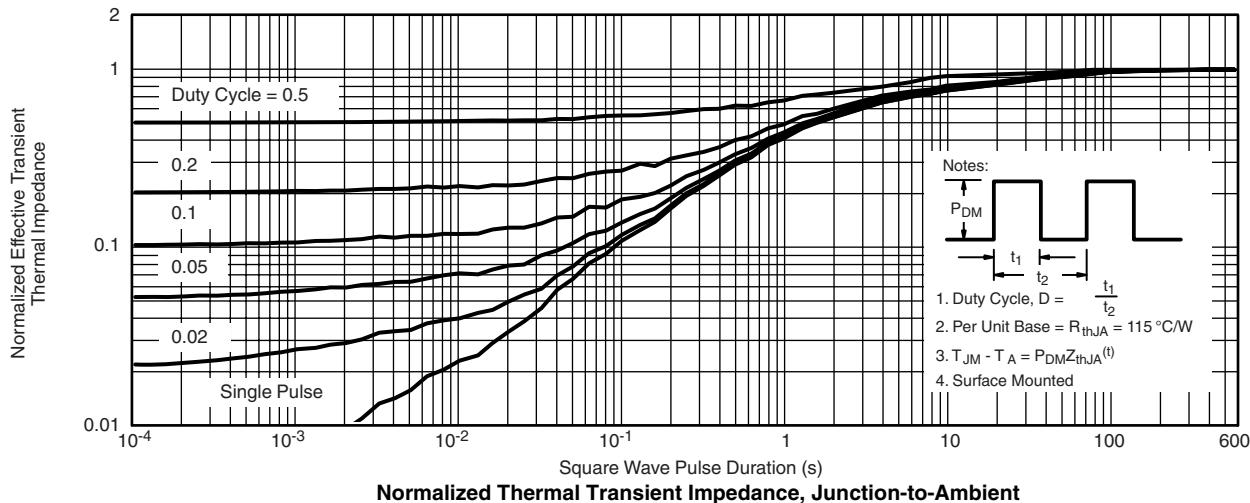
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <http://www.vishay.com/ppg?70811>.

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